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## Ultra Low Power Rail-to-Rail Output Operational Amplifier

# Preliminary

# OP186

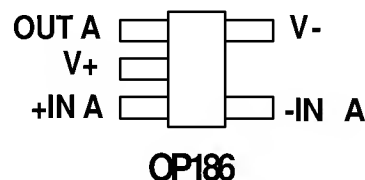
### FEATURES

- Low Supply Current: 4  $\mu$ A Max
- Single-Supply Operation: 2.7 to 12 Volts
- Wide Input Voltage Range
- Rail-to-Rail Output Swing
- No Phase Reversal

### APPLICATIONS

- Comparator
- Battery Powered Instrumentation
- Safety Monitoring
- Remote Sensors
- Low Voltage Strain Gage Amplifiers

### 5-Lead SOT (RT Suffix)



### GENERAL DESCRIPTION

The OP186 is a single **ultra low power** single-supply, amplifier featuring rail-to-rail outputs. Specified at 3 volt, and **5 volt single supply** as well as  $\pm 5$  volt dual supplies, it is guaranteed to operate from as low as 2.7 volts.

Fabricated on Analog Device's CBCMOS process, the OP186 features a bipolar input and an output that swings to within millivolts of the supplies and continues to sink or source current all the way to the supplies.

Applications for these amplifiers include safety monitoring, portable equipment, battery and power supply control, and as signal conditioning and interface for transducers in very low power systems.

The output's ability to swing rail-to-rail and not increase supply current when the output is driven to a supply, enables the OP186 to be used as a comparator in very low power systems.

The OP186 is specified over the extended industrial ( $-40^{\circ}$  to  $+125^{\circ}\text{C}$ ) temperature range. The OP186 is available in the SOT23 package.

### REV. 0

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One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106, U.S.A.  
Tel: 617/329-4700  
Fax: 617/326-8703  
World Wide Web Site: <http://www.analog.com>  
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ELECTRICAL SPECIFICATIONS (@  $V_S=+3.0V$ ,  $V_{CM} = 0.1V$ ,  $T_A=+25^\circ C$  unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
<b>INPUT CHARACTERISTICS</b>						
Offset Voltage	$V_{OS}$	$-40^\circ \leq T_A \leq +125^\circ C$			4	mV
Input Bias Current	$I_B$	$-40^\circ \leq T_A \leq +125^\circ C$		3.2		nA
Input Offset Current	$I_{OS}$	$-40^\circ \leq T_A \leq +125^\circ C$				nA
Input Voltage Range		$-40^\circ \leq T_A \leq +125^\circ C$	0			V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = 0$ to 2.0V $-40^\circ \leq T_A \leq +125^\circ C$			2	dB
Large Signal Voltage Gain	$A_{VO}$	$R_L = 1M\Omega$ , $V_O = 0.3$ to 2.7V $-40^\circ \leq T_A \leq +125^\circ C$				V/mV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$					$\mu V/^\circ C$
Bias Current Drift	$\Delta I_B/\Delta T$					pA/°C
Offset Current Drift	$\Delta I_{OS}/\Delta T$					pA/°C
<b>OUTPUT CHARACTERISTICS</b>						
Output Voltage High	$V_{OH}$	$R_L = 100k\Omega$ to Gnd. $-40^\circ C$ to $+125^\circ C$	2.95 2.90	2.99 2.98		V V
Output Voltage Low	$V_{OL}$	$R_L = 100k\Omega$ to V+ $-40^\circ C$ to $+125^\circ C$		10	35	mV mV
Short Circuit Limit	$I_{SC}$	$-40^\circ C$ to $+125^\circ C$		$\pm 2$		mA mA
<b>POWER SUPPLY</b>						
Power Supply Rejection Ratio	PSRR	$V_S = 2.7V$ to 12 V $-40^\circ \leq T_A \leq +125^\circ C$				dB dB
Supply Current/Amplifier	$I_{SY}$	$-40^\circ \leq T_A \leq +125^\circ C$		4		$\mu A$
<b>DYNAMIC PERFORMANCE</b>						
Slew Rate	SR	$R_L = 100k\Omega$ , $C_L = 50pF$		28		V/ms
Turn On Time		$A_V = 1$ , $V_O = 1$				$\mu s$
Turn On Time		$A_V = 20$ , $V_O = 1$				$\mu s$
Settling Time	$t_s$	To 0.01%				$\mu s$
Gain Bandwidth Product	GBP					kHz
Phase Margin	$\phi_o$					degrees
<b>NOISE PERFORMANCE</b>						
Voltage Noise	$e_{n\text{ p-p}}$	0.1 to 10 Hz				$\mu V_{\text{p-p}}$
Voltage Noise Density	$e_n$	$f = 1kHz$		110		nV/ $\sqrt{Hz}$
Current Noise Density	$i_n$					pA/ $\sqrt{Hz}$

# ELECTRICAL SPECIFICATIONS (@ $V_S=+5.0V$ , $V_{CM} = 0.1V$ , $T_A=+25^{\circ}C$ unless otherwise noted. Note 1)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
<b>INPUT CHARACTERISTICS</b>						
Offset Voltage	$V_{OS}$	Note 2 $-40^{\circ} \leq T_A \leq +125^{\circ}C$			4 1.0	mV mV
Input Bias Current	$I_B$	$-40^{\circ} \leq T_A \leq +125^{\circ}C$		3.2		nA nA
Input Offset Current	$I_{OS}$	$-40^{\circ} \leq T_A \leq +125^{\circ}C$		0.1	8 16	nA nA
Input Voltage Range			0		4	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = 0$ to 4.0V $-40^{\circ} \leq T_A \leq +125^{\circ}C$	76 76			dB dB
Large Signal Voltage Gain	$A_{VO}$	$R_L = 1\text{ M}\Omega$ , $V_O = 0.5$ to 4.5V $-40^{\circ} \leq T_A \leq +125^{\circ}C$				V/mV V/mV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	$-40^{\circ} \leq T_A \leq +125^{\circ}C$				$\mu V/^{\circ}C$
Bias Current Drift	$\Delta I_B/\Delta T$					pA/ $^{\circ}C$
Offset Current Drift	$\Delta I_{OS}/\Delta T$					pA/ $^{\circ}C$
<b>OUTPUT CHARACTERISTICS</b>						
Output Voltage High	$V_{OH}$	$R_L = 100k\Omega$ to Gnd. $-40^{\circ}C$ to $+125^{\circ}C$	4.95 4.90	4.99 4.98		V V
Output Voltage Low	$V_{OL}$	$R_L = 100k\Omega$ to $V_+$ , $-40^{\circ}C$ to $+125^{\circ}C$		4.5	10 35	mV mV
Short Circuit Limit	$I_{SC}$	$-40^{\circ}C$ to $+125^{\circ}C$		$\pm 2$		mA mA
<b>POWER SUPPLY</b>						
Power Supply Rejection Ratio	PSRR	$V_S = 2.7V$ to 12V $-40^{\circ} \leq T_A \leq +125^{\circ}C$	76 76	96 95		dB dB
Supply Current/Amplifier	$I_{SY}$	$-40^{\circ} \leq T_A \leq +125^{\circ}C$		3.5		$\mu A$
<b>DYNAMIC PERFORMANCE</b>						
Slew Rate	SR	$R_L = 100\text{ k}\Omega$ , $C_L = 50pF$		26		V/ms
Gain Bandwidth Product	GBP					kHz
Phase Margin	$\phi_o$					degrees
<b>NOISE PERFORMANCE</b>						
Voltage Noise	$e_{n\text{ p-p}}$	0.1 to 10 Hz				$\mu V_{\text{p-p}}$
Voltage Noise Density	$e_n$	$f = 1\text{ kHz}$		110		nV/ $\sqrt{\text{Hz}}$
Voltage Noise Density	$e_n$	$f = 10\text{ kHz}$				nV/ $\sqrt{\text{Hz}}$
Current Noise Density	$i_n$					pA/ $\sqrt{\text{Hz}}$

NOTE 1: +5 volt specifications are guaranteed by +3 and  $\pm 5$  volt testing.

Note 2:  $V_{OS}$  is tested under a no load condition.

ELECTRICAL SPECIFICATIONS (@  $V_S = \pm 5V$ ,  $T_A = +25^\circ C$  unless otherwise noted.)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
<b>INPUT CHARACTERISTICS</b>						
Offset Voltage	$V_{OS}$	$-40^\circ \leq T_A \leq +125^\circ C$			4	mV
Input Bias Current	$I_B$	$-40^\circ \leq T_A \leq +125^\circ C$		3.2		nA
Input Offset Current	$I_{OS}$	$-40^\circ \leq T_A \leq +125^\circ C$		0.1	8	nA
Input Voltage Range			-5		16	V
Common-Mode Rejection	CMRR	$V_{CM} = -5.0$ to $+4.0V$ $-40^\circ \leq T_A \leq +125^\circ C$	75		+4	dB
Large Signal Voltage Gain	$A_{VO}$	$R_L = 1\text{ M}\Omega$ , $V_O = \pm 4.0V$ , $-40^\circ \leq T_A \leq +125^\circ C$	67	6.5		dB
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$					$\mu V/^\circ C$
Bias Current Drift	$\Delta I_B/\Delta T$					$pA/^\circ C$
Offset Current Drift	$\Delta I_{OS}/\Delta T$					$pA/^\circ C$
<b>OUTPUT CHARACTERISTICS</b>						
Output Voltage Swing	$V_O$	$R_L = 100k\Omega$ to Gnd. $-40^\circ C$ to $+125^\circ C$	$\pm 4.93$ $\pm 4.90$	$\pm 4.99$ $\pm 4.98$		V V
Short Circuit Limit	$I_{SC}$	$-40^\circ C$ to $+125^\circ C$				mA mA
<b>POWER SUPPLY</b>						
Power Supply Rejection Ratio	PSRR	$V_S = \pm 25V$ to $\pm 6V$ $-40^\circ \leq T_A \leq +125^\circ C$	76 70			dB dB
Supply Current/Amplifier	$I_{SY}$	$V_O = 0V$ $-40^\circ \leq T_A \leq +125^\circ C$		3.3	5	$\mu A$ $\mu A$
<b>DYNAMIC PERFORMANCE</b>						
Slew Rate	$\pm SR$	$R_L = 100\text{ k}\Omega$ , $C_L = 50pF$		35		V/ms
Saturation Recovery Time						ms
Gain Bandwidth Product	GBP			58		kHz
Phase Margin	$\phi_o$			56		degrees
<b>NOISE PERFORMANCE</b>						
Voltage Noise	$e_{n\text{ p-p}}$	0.1 to 10 Hz				$\mu V_{\text{p-p}}$
Voltage Noise Density	$e_n$	$f = 1\text{ kHz}$		110		$nV/\sqrt{Hz}$
Voltage Noise Density	$e_n$	$f = 10\text{ kHz}$		80		$nV/\sqrt{Hz}$
Current Noise Density	$i_n$					$pA/\sqrt{Hz}$

**ABSOLUTE MAXIMUM RATINGS**

Supply Voltage..... +16V  
 Input Voltage..... Gnd to Vs+10V  
 Differential Input Voltage.....  $\pm 3.5$ V  
 Output Short-Circuit Duration to Gnd<sup>1</sup>..... Indefinite  
 Storage Temperature Range  
     RT Package..... -65°C to +150°C  
 Operating Temperature Range  
     OP186G..... -40°C to +125°C  
 Junction Temperature Range  
     RT Package..... -65°C to +150°C  
 Lead Temperature Range (Soldering, 60 sec.)..... +300°C

Package Type	$\theta_{JA}$ <sup>1</sup>	$\theta_{JC}$	Units
5-Lead SOT23 (RT)			°C/W

**NOTES**

<sup>1</sup>  $\theta_{JA}$  is specified for the worst case conditions, i.e.,  $\theta_{JA}$  is specified for device soldered in circuit board for SOT packages.

**ORDERING GUIDE**

Model	Temperature Range	Package Description	Package Option
OP186GRT	-40°C to +125°C	5-Lead SOT23	RT-5